

# **High Efficient Surface Mount Rectifiers**

#### FEATURES

- Glass passivated junction chip
- Ideal for automated placement
- Low profile package
- Low power loss, high efficiency
- Fast switching for high efficiency
- Moisture sensitivity level: level 1, per J-STD-020
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21 definition

### **MECHANICAL DATA**

#### Case: Sub SMA





Sub SMA

Molding compound, UL flammability classification rating 94V-0 Base P/N with suffix "G" on packing code - green compound (halogen-free) Base P/N with prefix "H" on packing code - AEC-Q101 qualified **Terminal:** Matte tin plated leads, solderable per JESD22-B102 Meet JESD 201 class 1A whisker test with prefix "H" on packing code meet JESD 201 class 2 whisker test **Polarity:** Indicated by cathode band **Weight:** 0.019 g (approximately)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS (T <sub>A</sub> =25°C unless otherwise noted)										
DADAMETED	SYMPOL HS	HS	HS	HS	HS	HS	HS	HS	HS	
PARAMETER	SYMBOL	1AL	1BL	1DL	1FL	1GL	1JL	1KL	1ML	UNIT
Marking code		HAL	HBL	HDL	HFL	HGL	HJL	HKL	HML	
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	50	100	200	300	400	600	800	1000	V
Maximum RMS voltage	V <sub>RMS</sub>	35	70	140	210	280	420	560	700	V
Maximum DC blocking voltage	V <sub>DC</sub>	50	100	200	300	400	600	800	1000	V
Maximum average forward rectified current	I <sub>F(AV)</sub>	1 A								
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	30 A								
Maximum instantaneous forward voltage (Note 1) @ 1 A	V <sub>F</sub>	0.95 1.3			1.7		V			
Maximum reverse current @ rated VR $T_J$ =25 $^{\circ}C$ $T_J$ =125 $^{\circ}C$	I <sub>R</sub>	5 150			μA					
Typical junction capacitance (Note 2)	Cj	20 15		pF						
Maximum reverse recovery time (Note 3)	Trr	50 75			ns					
Typical thermal resistance	R <sub>θjA</sub>	100		<sup>o</sup> C/W						
Operating junction temperature range	TJ	- 55 to +150 °C			°C					
Storage temperature range	T <sub>STG</sub>	- 55 to +150 °C		°C						

Note 1: Pulse test with PW=300µs, 1% duty cycle

Note 2: Measured at 1 MHz and Applied VR=4.0 Volts.

Note 3: Reverse Recovery Test Conditions:  $I_F$ =0.5A,  $I_R$ =1.0A,  $I_{RR}$ =0.25A



**Taiwan Semiconductor** 

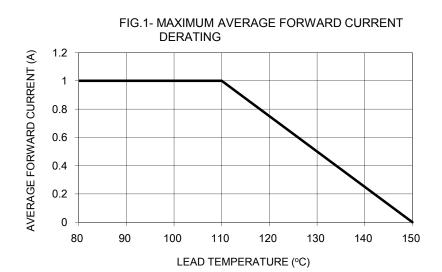
ORDERING INFORMATION					
PART NO.	AEC-Q101	PACKING CODE	GREEN COMPOUND	PACKAGE	PACKING
	QUALIFIED		CODE		
HS1xL (Note 1) Prefix "H"		RU	-	Sub SMA	1,800 / 7" Plastic reel (8mm tape)
		RV		Sub SMA	3,000 / 7" Plastic reel (8mm tape)
	RT		Sub SMA	7,500 / 13" Paper reel (8mm tape)	
	MT		Sub SMA	7,500 / 13" Plastic reel (8mm tape)	
	RQ		Sub SMA	10,000 / 13" Paper reel (8mm tape)	
	Drofix "Ll"	MQ	Suffix "G"	Sub SMA	10,000 / 13" Plastic reel (8mm tape)
		R3		Sub SMA	1,800 / 7" Plastic reel (12mm tape)
		RF		Sub SMA	3,000 / 7" Plastic reel (12mm tape)
		R2		Sub SMA	7,500 / 13" Paper reel (12mm tape)
		M2		Sub SMA	7,500 / 13" Plastic reel (12mm tape)
		RH		Sub SMA	10,000 / 13" Paper reel (12mm tape)
		MH		Sub SMA	10,000 / 13" Plastic reel (12mm tape)

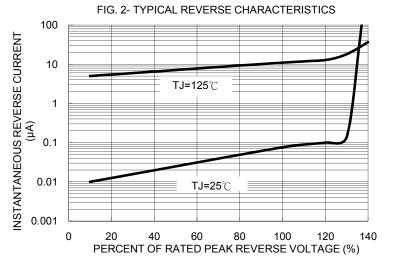
Note 1: "x" defines voltage from 50V (HS1AL) to 1000V (HS1ML)

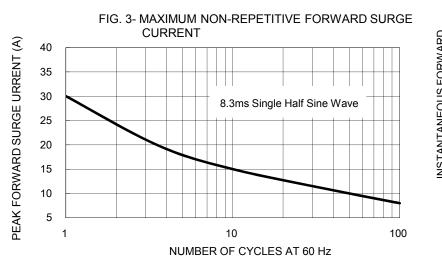
EXAMPLE						
PREFERRED P/N	PART NO.	AEC-Q101 QUALIFIED	PACKING CODE	GREEN COMPOUND CODE	DESCRIPTION	
HS1JL RU	HS1JL		RU			
HS1JL RUG	HS1JL		RU	G	Green compound	
HS1JLHRU	HS1JL	Н	RU		AEC-Q101 qualified	

### **RATINGS AND CHARACTERISTICS CURVES**

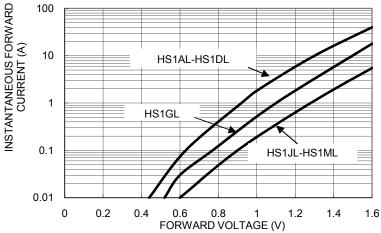
(TA=25 $^{\circ}$ C unless otherwise noted)













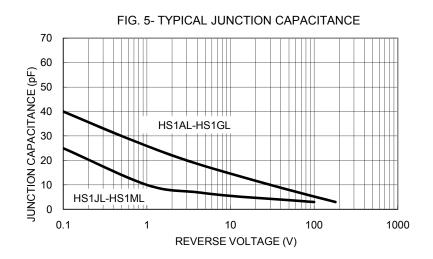
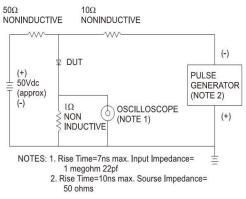
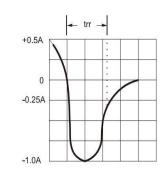
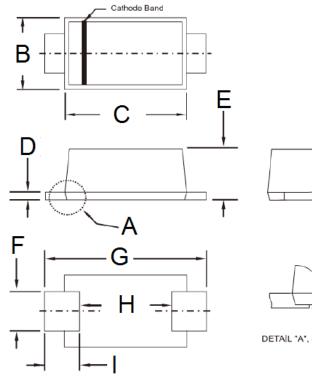


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM







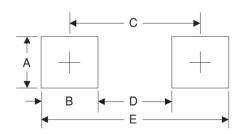


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#### DETAIL "A", SCALE=20/1

DIM.	Unit	(mm)	Unit (	(inch)
Dilvi.	Min Max		Min	Max
В	1.70	1.90	0.067	0.075
С	2.70	2.90	0.106	0.114
D	0.16	0.30	0.006	0.012
E	1.23	1.43	0.048	0.056
F	0.80	1.20	0.031	0.047
G	3.40	3.80	0.134	0.150
Н	2.45	2.60	0.096	0.102
I	0.35	0.85	0.014	0.033
J	0.00	0.10	0.000	0.004

## SUGGESTED PAD LAYOUT



P/N

YW

G

F

Symbol	Unit (mm)	Unit (inch)
А	1.4	0.055
В	1.2	0.047
С	3.1	0.122
D	1.9	0.075
E	4.3	0.169

# **MARKING DIAGRAM**



- = Marking Code = Green Compound
- = Date Code
- = Factory Code



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